

MQ110-A1-UV-Hk

AO Modulator/Shifter

High power 355 nm modulator

• High power • Linear Polarization

These modulators have been specially designed for applications for which TeO₂ cannot be used. They cover the UV range up to Visible range. Suitable for DPSS 355 nm or UV AR+ lasers.

They can also be used as fixed frequency shifters @110 MHz, as well as variable frequency shifters or deflectors with a frequency range up to 110 +/- 15 MHz.

Specifications

Material-Acoustic mode	Fused silica UV grade
Acoustic Velocity	V=5960 m/s
Optical Wavelength range	325-442 nm
Transmission	> 95 %
Optical Input / Output polarizations	Linear ⊥
Aperture	1 x 1 mm ²
Carrier frequency / Frequency shift	110 MHz
Separation angle	> 6 mrd (<i>Scan angle over 30 MHz: 1.8 mrd @355nm</i>)
Diffraction efficiency (with TEM₀₀ beam, M² ≤ 1.1)	Nom 90 % @355 nm, @0.7 mm beam dia
Rise time	110 ns /mm (min 30 ns)
Amplitude modulation bandwidth	> 6 MHz (-3 dB, @0.7 mm)
Static extinction ratio	> 1000/1
Max optical power density	> 10 W / mm ² @355 nm
Input impedance	Nom 50 Ω
V.S.W.R.	Nom < 1.5/1
RF Power	Nom 3 Watts
Connector	SMA
Size / Weight	(Lxhx)
Operating Temperature	10 to 40 °C



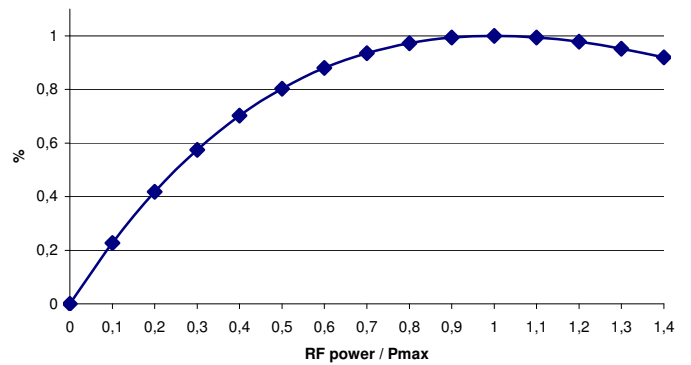
→ Separation angle ($\Delta\theta$) is wavelength (λ) sensitive:

$$\Delta\theta = \frac{\lambda F}{V}$$

→ RF power (P) is wavelength (λ) sensitive:

$$\frac{P_1}{P_2} = \frac{\lambda_1^2}{\lambda_2^2}$$

Relative Diffraction Efficiency vs RF Power



OPTIONS

Frequency range 110+/-15MHz

Nominal efficiency over 110+/-15MHz > 70%

Outline Drawing

sizes in mm

